Effects of baryon number fluctuation around QCD critical point

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QCD phase diagram



Fukushima and Hatsuda(2010)

- Chiral phase transition
- Order parameter $\langle \bar{\psi}\psi \rangle$
- 1st order boundary and its end point (2nd order)



Critical region



- Critical point is not point like.
- Susceptibility is enhanced near the critical point.
- We need to evaluate the size of the critical region.



Effective potential





- Effective potential as a function of order parameter $\sigma \sim \bar{\psi}\psi$
- A Soft mode accompanying the CP is sigma mode?

Spectral functions near CP



H. Fujii, M. Ohtani Phys.Rev. D70 (2004) 014016

• The soft mode is a linear combination of sigma and baryon-number density (particle-hole mode).



<u>H. Fujii</u>, <u>M. Ohtani</u> Phys.Rev. D70 (2004) 014016 D. Son and M. Stephanov, Phys. Rev. D 70, 056001 (2004).

- A coupling between chiral condensate and quarknumber density is essential.
- We have to evaluate the thermodynamic potential with the mixing.



$$\mathcal{L} = \bar{\psi}[i\partial - g_s(\sigma + i\gamma_5 \vec{\tau} \cdot \vec{\pi}) + (g_d \varphi \gamma_0)]\psi + \frac{1}{2}(\partial_\mu \sigma)^2 + \frac{1}{2}(\partial_\mu \vec{\pi})^2 + (\frac{1}{2}(\partial_\mu \varphi)^2) - a(\sigma^2 + \vec{\pi}^2) - b(\sigma^2 + \vec{\pi}^2)^2 - (\frac{m_\varphi}{2}\varphi^2) + c\sigma$$

- We introduce new filed φ (baryon-number density with appropriate normalization).
- g_d is density coupling which is familiar in Walecka model (σ - ω model).
- quark-quark interaction is attractive.



Parameters

$\mathcal{L} = \bar{\psi}[i\partial \!\!\!/ - g_s(\sigma + i\gamma_5 \vec{\tau} \cdot \vec{\pi}) + g_d \varphi \gamma_{\bullet}]\psi + \frac{1}{2}(\partial_\mu \sigma)^2 + \frac{1}{2}(\partial_\mu \vec{\pi})^2 + \frac{1}{2}(\partial_\mu \varphi)^2 - \frac{a(\sigma^2 + \vec{\pi}^2) - b(\sigma^2 + \vec{\pi}^2)^2 - \frac{m_\varphi}{2}\varphi^2 + c\sigma}$

- a, b,c and g_s are fixed by vacuum physical value such as m_{π} , f_{π} , Mo~600 [MeV] and Mq~300[MeV].
- We fix M_{ϕ} and vary g_{d} .
- A ratio (g_d/M_{ϕ}) controls a strength of the mixing.



Functional-RG

$$k\partial_k\Gamma_k[\varphi] = \frac{1}{2}\operatorname{Tr}\left[\frac{k\partial_k R_{kB}}{R_{kB} + \Gamma_k^{(0,2)}[\varphi]}\right] - \operatorname{Tr}\left[\frac{k\partial_k R_{kF}}{R_{kF} + \Gamma_k^{(2,0)}[\varphi]}\right]$$

C. Wetterich, Phys. Lett. B301, 90 (1993)

- $$\begin{split} \Gamma_k[\phi] : \text{effective potential at scale } k & S[\phi] + \frac{1}{2} R_k \phi^2 \\ R_k(p) \sim k^2 \text{ for } p^2 << k^2 \\ R_k(p) \sim 0 \text{ for } p^2 >> k^2 \end{split}$$
- R_k prevents the propagation of the mode q < k.

$$\Gamma_{k=\Lambda}[\phi] = S[\phi] \qquad \text{classical}$$

$$\int \Gamma_{k=0}[\phi] = \Gamma[\phi] \qquad \text{quantum}$$



How to solve it

$$\Gamma_k^{LPA} = \text{Kinetic part} + U_k(\sigma^2 + \pi^2, \varphi) - c\sigma$$



- Assume a functional form of the effective action (Local potential approximation[LPA])
- Solve coupled ordinary differential equations for U_k(σ_n,φ_m): (grid method)



Phase Structure



- QCD CP exists for finite g_d.
- The position of CP slightly moves to higher T and lower µ direction.



Potential on the CP



• The flat direction changes to the φ direction with g_d increasing.



Susceptibility



• The critical region is drastically expanded with g_d .



- We calculate M+ and M- (eigenvalue of matrix M).
- M- corresponds to curvature of the flat direction.



Curvature mass



- We see a kind of level repulsion between M+ and M- $(g_d \neq 0)$.
- M- is decreased by the level repulsion.



Curvature mass



• Small M- region is also expanded.



- We have considered the QCD critical point and its critical region.
- We have considered the model which includes the baryon-density mode as well as chiral modes.
- We have seen the expansion of critical region with the coupling increasing.

• We will calculate the higher moments of the quark or charge number density.



• Thank you for your attendtion